V60H150PW-M3

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.52$ V at $I_F = 10$ A

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

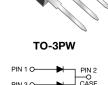
M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60H150PW	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	150	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	٨	
	per diode		30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	260	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	





2 x 30 A

150 V

260 A

0.65 V

175 °C

TO-3PW

Dual common cathode

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

I_{FSM} V_F at $I_F = 30$ A

T_J max.

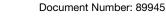
Package **Diode variation**

Downloaded from Arrow.com.



RoHS

COMPLIANT HALOGEN FREE





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 10 \text{ A}$	T _A = 25 °C	V _F ⁽¹⁾	0.66	-	V	
	I _F = 15 A			0.72	-		
	I _F = 30 A			0.80	0.93		
	$I_F = 10 \text{ A}$	T _A = 125 °C		0.52	-		
	I _F = 15 A			0.56	-		
	I _F = 30 A			0.65	0.73		
Reverse current per diode	V _R = 120 V	T _A = 25 °C	I _R ⁽²⁾	1.7	-	μA	
		T _A = 125 °C		2.6	-	mA	
	V _R = 150 V	T _A = 25 °C		_	250	μA	
		T _A = 125 °C		3.7	36	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 20\ ms$

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V60H150PW	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	0.9	°C/W	
	per device		0.6	0/10	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	V60H150PW-M3/4W	4.5	4W	30/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

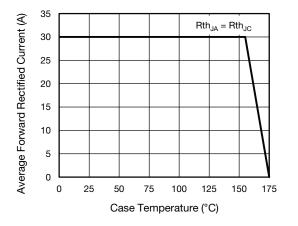


Fig. 1 - Maximum Forward Current Derating Curve

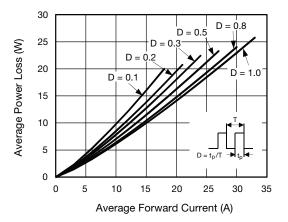
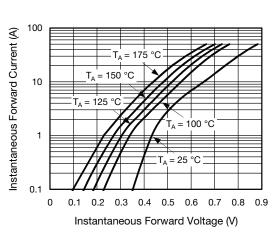


Fig. 2 - Forward Power Loss Characteristics Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

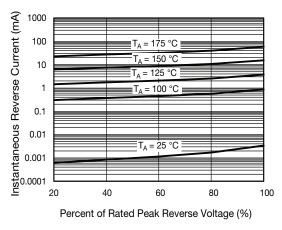


Fig. 4 - Typical Reverse Characteristics Per Diode



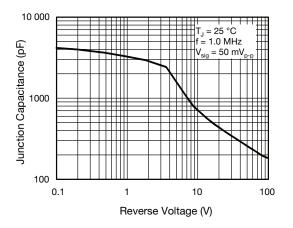


Fig. 5 - Typical Junction Capacitance Per Diode

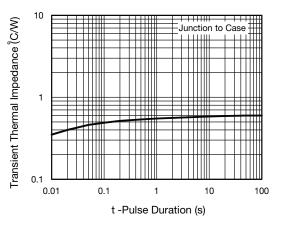
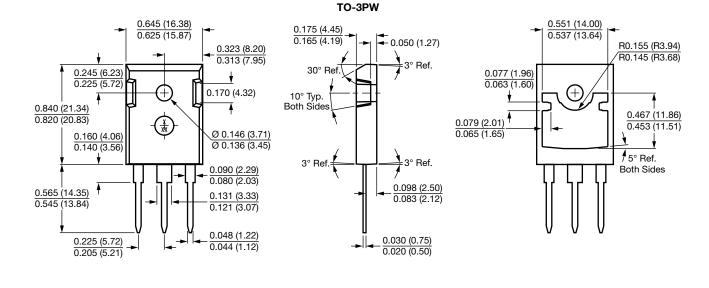


Fig. 6 - Typical Transient Thermal Impedance Per Device



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